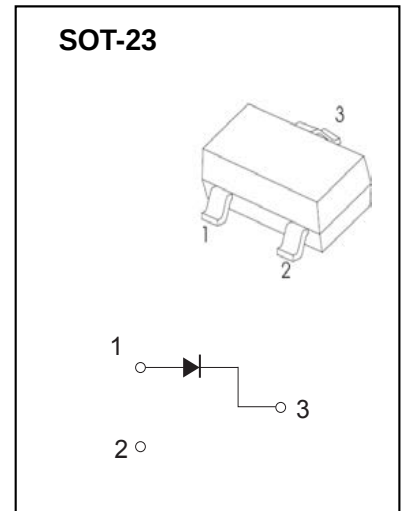
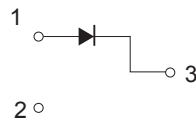
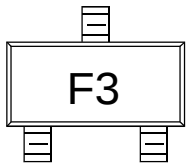


SOT-23 Plastic-Encapsulate Diodes**1SS193****Switching Diodes****FEATURES**

- Fast reverse recovery time
- Low forward voltage

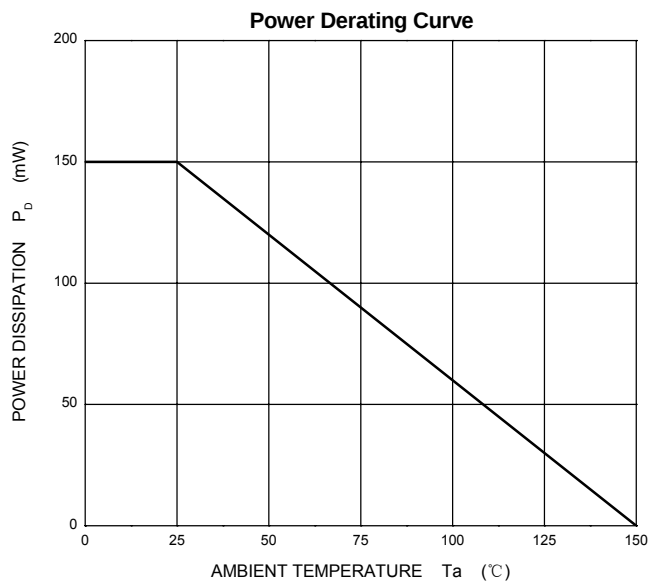
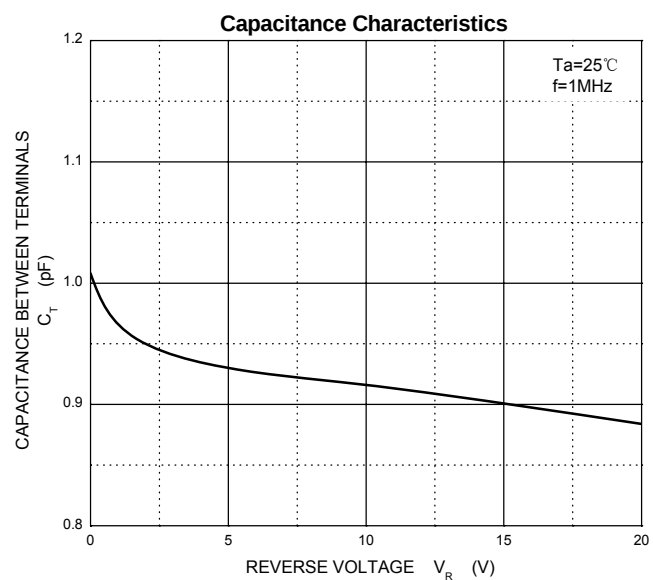
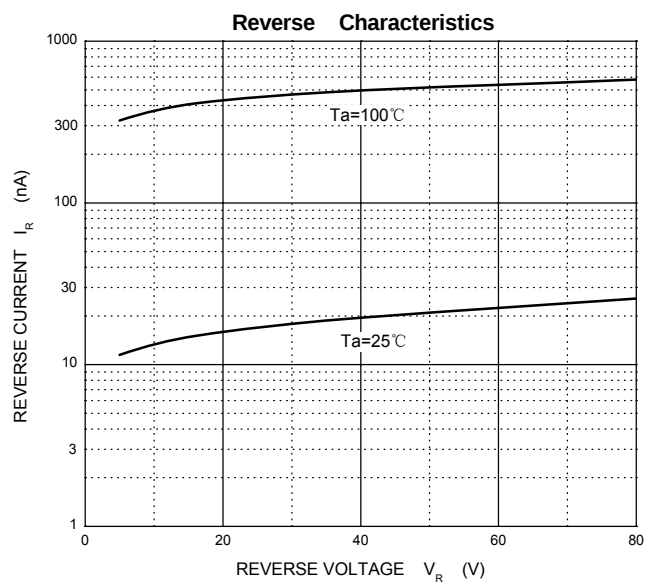
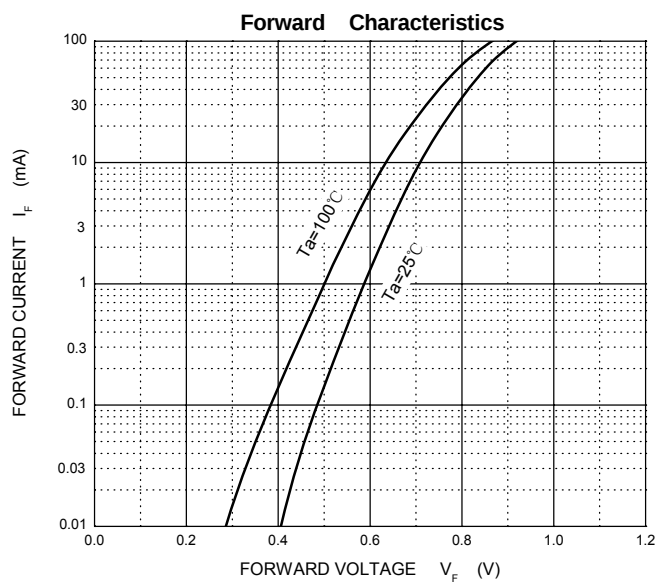
MARKING**Equivalent Circuit****MAXIMUM RATINGS** ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	85	V
DC Blocking Voltage	V_R	80	V
Forward Continuous Current	I_{FM}	300	mA
Average Rectified Output Current	I_O	100	mA
Non-Repetitive Peak Forward Surge Current @ $t=8.3\text{ms}$	I_{FSM}	2.0	A
Power Dissipation	P_D	150	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	833	$^{\circ}\text{C/W}$
Operation Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Reverse breakdown voltage	$V_{(BR)}$	80			V	$I_R=100\mu\text{A}$
Forward voltage	V_{F1}		0.60		V	$I_F=1\text{mA}$
	V_{F2}		0.72		V	$I_F=10\text{mA}$
	V_{F3}		0.90	1.2	V	$I_F=100\text{mA}$
Reverse current	I_{R1}			0.1	μA	$V_R=30\text{V}$
	I_{R2}			0.5	μA	$V_R=80\text{V}$
Capacitance between terminals	C_T		0.9	3.0	pF	$V_R=0, f=1\text{MHz}$
Reverse recovery time	t_{rr}		1.6	4.0	ns	$I_F=I_R=10\text{mA}, I_{rr}=0.1 \times I_R$

Typical Characteristics



Package Outline Dimensions (SOT-23)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

Suggested Pad Layout (SOT-23)



- Note:
- 1.Controlling dimension:in millimeters.
 - 2.General tolerance:± 0.05mm.
 - 3.The pad layout is for reference purposes only.